



CHENMKO ENTERPRISE CO.,LTD

Lead free devices

**SURFACE MOUNT
High Voltage NPN Transistor**

VOLTAGE 300 Volts CURRENT 500 mAmpere

CHTA42LPT

APPLICATION

- * Small Signal Amplifier .

FEATURE

- * Surface mount package. (SC-59/SOT-346)
- * Low saturation voltage $V_{CE(sat)}=0.5V$ (max.)($I_C=20mA$)
- * Low cob. Cob=3.0pF(Typ.)
- * $P_D= 300mW$ (mounted on ceramic substrate).
- * High saturation current capability.

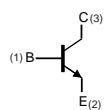
CONSTRUCTION

- * NPN Silicon Transistor
- * Epitaxial planner type

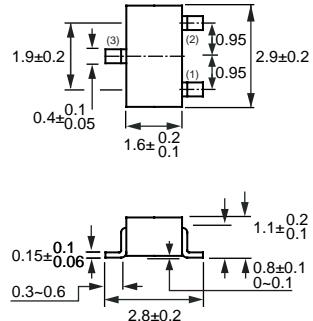
MARKING

- * NB

CIRCUIT



SC-59/SOT-346



Dimensions in inches and (millimeters)

SC-59/SOT-346

MAXIMUM RATINGS (At $T_A = 25^\circ C$ unless otherwise noted)

RATINGS	CONDITION	SYMBOL	MIN.	MAX.	UNITS
Collector - Base Voltage	Open Emitter	V_{CBO}	-	300	Volts
Collector - Emitter Voltage	Open Base	V_{CEO}	-	300	Volts
Emitter - Base Voltage	Open Collector	V_{EBO}	-	6.0	Volts
Collector Current DC		I_C	-	500	mAmps
Peak Collector Current		I_{CM}	-	500	mAmps
Peak Base Current		I_{BM}	-	15	mAmps
Total Power Dissipation	$T_A \leq 25^\circ C$; Note 1	P_{TOT}	-	300	mW
Storage Temperature		T_{STG}	-55	+150	°C
Junction Temperature		T_J	-	+150	°C
Operating Ambient Temperature		T_{AMB}	-55	+150	°C

Note

1. Transistor mounted on ceramic substrate 50mmX50mmx0.8t.
2. Measured at Pulse Width 300 us, Duty Cycle 2%.

RATING CHARACTERISTICS (CHTA42LPT)

ELECTRICAL CHARACTERISTICS (At TA = 25°C unless otherwise noted)

PARAMETERS	CONDITION	SYMBOL	MIN.	TYPE	MAX.	UNITS
Collector Cut-off Current	I _E =0; V _{CB} =200V	I _{CBO}	-	-	0.1	uA
Emitter Cut-off Current	I _C =0; V _{BE} =6.0V	I _{CEO}	-	-	0.1	uA
DC Current Gain	V _{CE} =10V; Note 1 I _c =1.0mA I _c =10mA I _c =30mA	h_{FE}	25 40 40	- - -	- - -	
Collector-Emitter Saturation Voltage	I _c =20mA; I _b =2mA	V _{CE(sat)}	-	-	0.5	Volts
Base-Emitter Saturatio Voltage	I _c =20mA; I _b =2mA	V _{BE(sat)}	-	-	0.9	Volts
Output Collector Capacitance	I _E =I _e =0; V _{CB} =20V; f=1MHz	C _{ob}	-	-	3.0	pF
Transition Frequency	I _c =10mA; V _{CE} =20V; f=100MHz	f _T	50	-	-	MHz

Note :

- Pulse test: t_p ≤ 300uSec; δ ≤ 0.02.

RATING CHARACTERISTIC CURVES (CHTA42LPT)

Figure 1. DC Current Gain

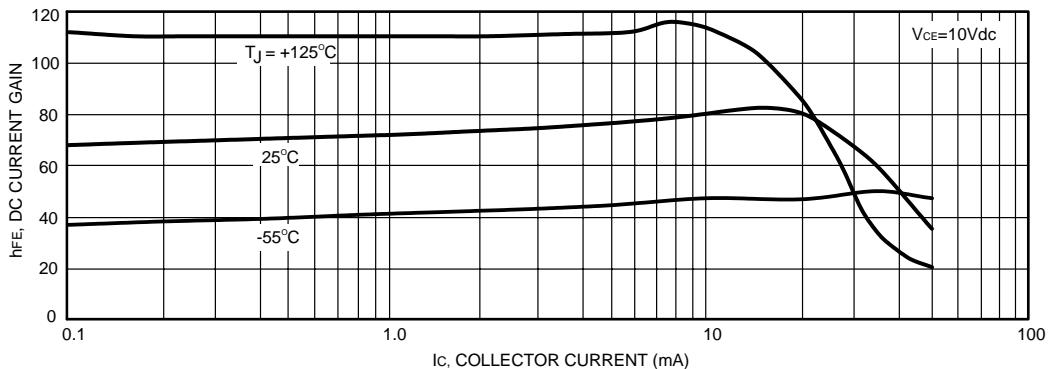


Figure 2. Capacitance

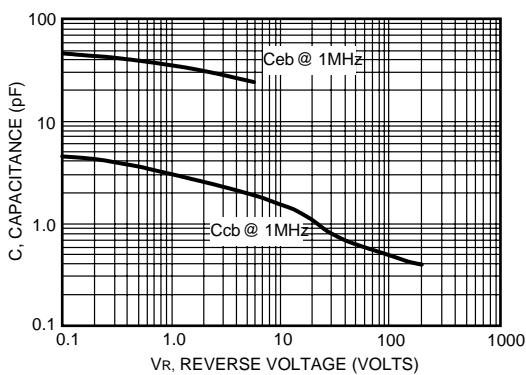


Figure 3. Current-Gain - Bandwidth

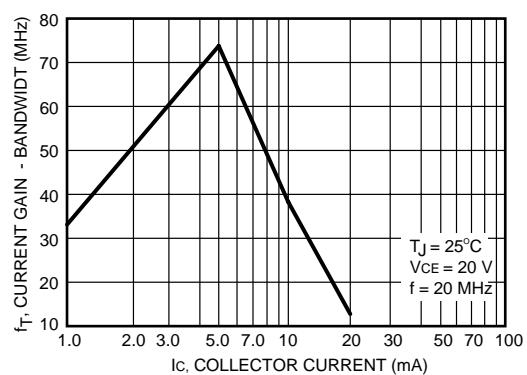


Figure 4. "ON" Voltages

